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Full length article

On the measurement of dislocations and dislocation substructures using EBSD and HRSD techniques

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#### A R T I C L E I N F O

#### ABSTRACT

Article Intropy Received 26 March 2019 Received in revised form 14 May 2019 Accepted 17 May 2019 Available online 7 June 2019

Keynowsk: Distocation density Metal planeticity Hection back-scatter diffraction (EBSD) High-resolution synchrotron diffraction (HSDI) Peak Invasiening The accumulation of the dislocations and development of dislocation structures in plastically deformed N201 is examined using dedicated analyses of Electron Back-Scatter Diffaction (EBSD) acquired pointation maps, and high-flexolution Synchronron Diffaction (HRSD) acquired patherms, the results show that the minimum detectable microstructure-averaged (bdfk) total dislocation density ( $\rho_{el}$ ) measured via HRSD is approximately EE13 m<sup>-1</sup>, while the minimum CAD density ( $\rho_{el}$ ) measured via LRSD is approximately 2E12 m<sup>-2</sup> — the BSD technique being more sensitive at low plantic strain. This highlights complementarity of the two techniques when attempting to quantify amount of plastic deformation (damage) in a material via a measurement of present dislocation and their structures. Furthermore, a relationship between EBSD-measured  $\rho_{el}$  and the size of IRSD-measured Coherently Scattering Domains (CSDS) has been mathematically derived — this allows for an estimation of the size of CSDs from EBSD-acquired orientation maps, and conversely an estimation of  $\rho_{el}$  from HBSD-measured size of CSDs. The measured evolution of  $\rho_{el}$ , and  $\rho_{el}$  is compared with plasticity theory models — the target restructures that Ashty's single-slip model underestimates the amount of GNDs ( $\rho_{el}$ ), while Taylor's model is correctly predicting the total amount of dislocation ( $\rho_{el}$ ) present in the material as a function of imparted plastic strain.

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#### **Dislocations & Sub-Grain Structure**



~ 50µm = 500000Å

⇒ To maintain compatible deformation across variously oriented grains in a polycrystalline aggregate, the voids and overlaps between the individual grains, which would otherwise appear due to the crystallites (grains) anisotropy are corrected by the storing a portion of dislocations in the form of geometrically-necessary dislocations (GNDs). Plastically deformed material also stores so-called statistically-stored dislocations (SSDs), which are stored by mutual random trapping. Both GNDs and SSDs arrange themselves into energetically favourable configurations, forming geometrically-necessary boundaries (GNBs) and incidental dislocation boundaries (IDBs), respectively.



#### Experiment



 $\Rightarrow$  EBSD orientation map showing the overall equiaxed grain structure of our solution-annealed Ni201 before testing.



 $\Rightarrow$  Interrupted tensile tests were performed to varying levels of imparted plastic strain. Samples were extracted from the gauge length for EBSD and HRSD measurement.

Ni-201

Ni	с	Si	Р	Fe	Mn	Cr	Мо	Cu	v	Nb	Ті	Al
bal.	<0.01	0.07	<0.01	0.03	<0.01	<0.01	<0.01	0.01	<0.01	<0.01	0.07	<0.01



# **EBSD Measurements**



## **Electron Back-Scatter Diffraction (EBSD)**



 $\Rightarrow$  EBSD, is a scanning electron microscope (SEM) based technique that gives crystallographic information about the microstructure of a sample.



 $\Rightarrow$  The data collected with EBSD is spatially distributed and is visualised in so-called EBSD orientation maps.



#### **EBSD & Dislocations**



 $\Rightarrow$  GNDs have a geometrical consequence giving rise to a curvature of the crystal lattice, which can be measured by EBSD technique. The crystal orientation ( $\phi_1$ ,  $\Phi$ ,  $\phi_2$ ) changes only when the electron beam crosses an array of GNDs that has a net non-zero Burger's vector.





#### **Lattice Curvature**



 $\Rightarrow$  A schematic representation of lattice curvature components calculation between two neighbouring crystals misoriented ( $\Delta\theta$ ) by a rotation around the common crystallographic axis [100]<sub>c</sub> ([uvw]<sub>c</sub>) and separated by pixel separation distance ( $\Delta x_2$ ). Note, that in this example:  $\kappa_{12} \approx \Delta \theta_1 / \Delta x_2$ , and  $\kappa_{22}$ ,  $\kappa_{32} = 0$ .

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 $\kappa_{12} \approx \frac{\Delta \theta_1}{\Delta x_2}; \kappa_{22} \approx \frac{\Delta \theta_2}{\Delta x_2}; \kappa_{32} \approx$ 

**06** W. Pantleon, Scripta Materialia, 58, 2008, pp. 994-997.

## **Lattice Curvature & GND Density**



**07** W. Pantleon, Scripta Materialia, 58, 2008, pp. 994-997.

# **Dislocation Types (fcc)**

 $(111)\langle 0\overline{1}1\rangle$ ´<u>1</u>11)(0<u>1</u>1) **6**×  $(\overline{1}11)\langle 101 \rangle$ **Burger's Vectors 12× Deformation Modes** ´<u>1</u>11)(101)  $\vec{b}_1 = \langle 0\bar{1}1 \rangle a / 2$  $(1\overline{1}1)\langle 011\rangle$  $\vec{b}_2 = \langle 101 \rangle a / 2$  $(111)\langle 011 
angle$  $\vec{b}_3 = \langle 011 \rangle a / 2$  $(1\overline{1}1)\langle\overline{1}01\rangle$  $\vec{b}_4 = \langle \overline{1}01 \rangle a / 2$ (111)(101)  $\vec{b}_{5} = \langle 110 \rangle a / 2$ (111)(110) $\vec{b}_6 = \langle 0 \overline{1} 0 \rangle a / 2$ (111)(110) (<u>1</u>11)(0<u>1</u>0)  $(\overline{1}\overline{1}1)\langle 0\overline{1}0\rangle$ 



$$6 \times$$
Line Vectors
$$\vec{b} \parallel \vec{t}$$

$$\vec{t}_{13} = \vec{b}_{1}$$

$$\vec{t}_{14} = \vec{b}_{2}$$

$$\vec{t}_{15} = \vec{b}_{3}$$

$$\vec{t}_{16} = \vec{b}_{4}$$

$$\vec{t}_{17} = \vec{b}_{5}$$

$$\vec{t}_{18} = \vec{b}_{6}$$

Number of Dislocation Types Edge = 12 Screw = 6  $18 \times 2 = 36$ fdislocations of opposite sign needs to be distinguished



## **Lower-Bound GND Density**



## **GND Density**



 $\Rightarrow$  Density of geometrically-necessary dislocations (GND,  $\rho_G$ ) maps calculated from the EBSD-measured Euler Angles ( $\phi_1, \Phi, \phi_2$ ) for specimens with 0% (as-received), 7.8% and 13.9% of imparted plastic strain.

 $\Rightarrow \text{Step size (h)} = 200 \text{ nm}$  $\Rightarrow \text{Magnification} = 153x$ 

⇒ Discrete measurements provide information on spatial distribution of GND across the microstructure.  $\Rightarrow$  GNDs arrange themselves into energetically favourable configurations forming geometricallynecessary boundaries (GNBs) subdividing grains into the sub-grains.



## **GND Spacing**



 $\Rightarrow$  Spacing between geometrically-necessary dislocations (GND, d<sub>G</sub>) recalculated from the GND density ( $\rho_G$ ) for specimens with 0% (as-received), 7.8% and 13.9% of imparted plastic strain.

 $\Rightarrow$  Non-uniform distribution of GNDs in the microstructure as GNDs arrange themselves into energetically favourable configurations subdividing grains into the sub-grains.





# **GND Density - High Resolution**



 $\Rightarrow$  Density of geometrically-necessary dislocations (GND,  $\rho_G$ ) calculated from the EBSD-measured Euler Angles ( $\phi_1$ ,  $\Phi$ ,  $\phi_2$ ).





 $\Rightarrow$  Spacing between geometrically-necessary dislocations (GND, d\_G) recalculated from the GND density ( $\rho_G$ ).

#### **GND Density**





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#### **Microstructure-Averaged GND Density**



⇒ Distribution (histogram) of discrete GND density ( $\rho_G$ ) measurements for specimen with 0% (as-received), 7.8% and 13.9% of imparted plastic strain ( $\epsilon_p$ ). ⇒ The variance of the GND density distribution describes the heterogeneity of the GND distribution across variously oriented grains within the microstructure, the mean can be then taken as the microstructure-averaged (bulk) GND density.



#### **Microstructure-Averaged GND Density**



 $\Rightarrow$  The development of the mean GND density as a function of number of analysed grains in GND density maps for specimen with 0% (as-received), 7.8% and 13.9% of imparted plastic strain ( $\epsilon_{\rm p}$ ).

**Log-Normal Distribution** 

$$f(\rho_G|\mu,\sigma) = \frac{1}{x\sigma\sqrt{2\pi}} exp\left(\frac{-(\ln(\rho_G) - \mu)^2}{2\sigma^2}\right)$$

MEAN of the lognormal distribution

$$\mathbf{m}(\rho_G) = exp\left(\mu + \frac{\sigma^2}{2}\right)$$

Mean & Variance

$$v(\rho_G) = exp(2\mu + \sigma^2)(exp(\sigma^2))$$

VARIANCE of the lognormal distribution

> $\Rightarrow$  Due to the increase in heterogeneity of GND distribution with imparted plastic strain, a larger number of grains is required to reach solution convergence.



#### **Microstructure-Averaged GND Density**



 $\Rightarrow$  The development of the **mean** GND density distribution as a function of imparted plastic strain ( $\epsilon_p$ ) for all tested specimens.

 $\Rightarrow$  The development of the **variance** of GND density distribution as a function of imparted plastic strain ( $\epsilon_p$ ) for all tested specimens.



# **GND Types in Solution**



 $\Rightarrow$  Map showing the ratio of screw dislocations to the total number of dislocations in the solution (6) for the specimen with 13.9% imparted plastic strain.



 $\Rightarrow$  Screw dislocation ratio as a function of imparted plastic strain for all tested specimens.

⇒ The uniqueness of the solution is not guaranteed. ⇒ Only pure edge and pure screw dislocations have been considered in the calculation.



# **HRSD Measurements**



#### **HRSD Set-Up**



Beam Size 200µm

 $\Rightarrow$  High-resolution synchrotron diffraction (HRSD) set-up at 1-ID high-energy beamline at the Advanced Photon Source (APS), Argonne National Laboratory (ANL).



 $\Rightarrow$  The total diffraction peak shape (which includes peak broadening)  $I_{TOTAL}$  of a is the convolution of the shape contribution caused by the size of coherently scattering domains (sub-grains)  $I_{SIZE}$ and the contribution caused by strain fields of present dislocations  $I_{STRAIN}$ .

 $\Rightarrow$  Convolution is defined as the invers Fourier transform of the product of the individual Fourier transform of the components.

$$I_{TOTAL} = I_{SIZE} * I_{STRAIN} = \mathcal{F}^{-1} \left( A^{Size} A^{Strain} \right)$$

$$A^{Size} = \mathcal{F}(I_{SIZE}) \quad A^{Strain} = \mathcal{F}(I_{STRAIN})$$
  
Size (sub-grain)  
contribution to the  
peak shape.  
Strain (dislocation  
contribution to the

peak shape.





#### **Diffraction Peak Broadening**



 $\Rightarrow$  The broadening due to the size of the coherently diffracting domains (sub-grains) is the same for all hkl diffraction peaks, while the broadening component due to the strain field of present dislocations varies between diffraction peaks. This variation in the strain (dislocation) broadening is not monotonous due to the anisotropic behaviour described by the dislocation contrast factors.



## **Diffraction Peak Broadening**





#### **Total Dislocation Density & Sub-Grain Size**



 $\Rightarrow$  Total dislocation density ( $\rho_T$ ) and size of the coherently scattering domains (SCDs) obtained by line profile analysis (LPA) of HRSD patterns as a function of imparted plastic strain ( $\varepsilon_p$ ) - open symbols represents individual measurements along the sample loading axis, and solid symbol represents the mean values.



# **EBSD + HRSD Measurements**



#### **EBSD- & HRSD- Measured Dislocation Density**



 $\Rightarrow$  Comparison of the HRND-measured total dislocation density ( $\rho_T$ ) and the EBSD-measured density of GNDs ( $\rho_G$ ), together with expected dislocation densities calculated using the modified Taylor's model, and single-slip Ashby's model.

 $\Rightarrow$  Both GNDs and SSDs contribute to the workhardening of the material.

 $\Rightarrow$  SSDs represent more than 80% of all the present dislocations.



### **GND Density & Size of CSDs**



 $\Rightarrow$  Comparison of the HRSD-measured size of CSDs (red circles) with EBSD-measured spacing of GNDs (d<sub>G</sub>) (blue squares), and the estimated minimum size of CSDs (green triangles) from EBSD-measured density of GNDs ( $\rho_G$ ).



 $\label{eq:starses} \begin{array}{l} \Rightarrow \mbox{This defines the connection between EBSD-} \\ \mbox{measured } \rho_{G} \mbox{ and HRSD-measured } \langle X \rangle_{A} \mbox{ one can then} \\ \mbox{estimate } \rho_{G} \mbox{ from } \langle X \rangle_{A}. \end{array}$ 



#### Conclusions

- $\Rightarrow$  EBSD measures the lower-bound  $\rho_G$ , while HRSD measures  $\rho_T$ .
- ⇒ The minimum detected  $\rho_T$  measured by HRSD is about **1E13 m<sup>-2</sup>**, while the minimum  $\rho_G$  measured by EBSD is about **2E12 m<sup>-2</sup>**.
- ⇒ EBSD is more sensitivity to the small amount of plastic deformation in the material, while HRSD gets more accurate with higher amount of plastic deformation.
- ⇒ There is a connection between EBSD-measured  $\rho_G$  and HRSD-measured size of CSDs ( $\langle X \rangle_A$ ).
- $\Rightarrow$  EBSD = Density of GNDs ( $\rho_G$ ), + estimate the minimum Size of CSDs
- $\Rightarrow$  HRSD = Total Dislocation Density ( $\rho_T$ ), size of CSDs ( $\langle X \rangle_A$ ), + estimate of minimum density of GNDs ( $\rho_G$ )







#### Thank you for your time and interest in this work. We hope you will find it useful.

Developed Matlab code for calculation of GNDs is available as a supplementary material with out Acta Materialia paper.